# MGSF1N02L, MVGSF1N02L

# MOSFET - Power: 750 mAmps, 20 Volts

# N-Channel SOT-23

These miniature surface mount MOSFETs low  $R_{DS(on)}$  assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc–dc converters and power management in portable and battery–powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

### Features

- Low R<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- MVGSF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable\*
- These Devices are Pb-Free and are RoHS Compliant

### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	20	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	± 20	Vdc
Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ( $t_p \le 10 \ \mu s$ )	I <sub>D</sub> I <sub>DM</sub>	750 2000	mA
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	400	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C

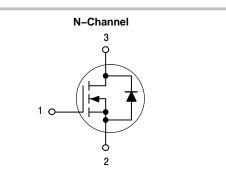
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



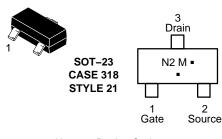
# **ON Semiconductor®**

www.onsemi.com

# 750 mAMPS, 20 VOLTS R<sub>DS(on)</sub> = 90 mΩ



MARKING DIAGRAM/ PIN ASSIGNMENT



N2 = Device Code

M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation and overbar may vary depending upon manufacturing location.

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MGSF1N02LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MVGSF1N02LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MGSF1N02L, MVGSF1N02L

Chai	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage ( $V_{GS} = 0$ Vdc, $I_D = 10 \mu$ Adc)	V <sub>(BR)DSS</sub>	20	-	-	Vdc	
Zero Gate Voltage Drain Current ( $V_{DS} = 20$ Vdc, $V_{GS} = 0$ Vdc) ( $V_{DS} = 20$ Vdc, $V_{GS} = 0$ Vdc, $T_J = 0$	I <sub>DSS</sub>			1.0 10	μAdc	
Gate-Body Leakage Current (V <sub>GS</sub>	I <sub>GSS</sub>	-	-	±100	nAdc	
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$	V <sub>GS(th)</sub>	1.0	1.7	2.4	Vdc	
$      Static Drain-to-Source On-Resista \\ (V_{GS} = 10 \ Vdc, \ I_D = 1.2 \ Adc) \\ (V_{GS} = 4.5 \ Vdc, \ I_D = 1.0 \ Adc) $	r <sub>DS(on)</sub>		0.075 0.115	0.090 0.130	Ω	
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V <sub>DS</sub> = 5.0 Vdc)	C <sub>iss</sub>	-	125	-	pF
Output Capacitance	(V <sub>DS</sub> = 5.0 Vdc)	C <sub>oss</sub>	-	120	-	
Transfer Capacitance	(V <sub>DG</sub> = 5.0 Vdc)	C <sub>rss</sub>	-	45	-	
SWITCHING CHARACTERISTICS	(Note 2)					
Turn-On Delay Time		t <sub>d(on)</sub>	_	2.5	_	ns
Rise Time	$(V_{DD} = 15 \text{ Vdc}, I_D = 1.0 \text{ Adc},$	t <sub>r</sub>	-	1.0	-	
Turn-Off Delay Time	R <sub>L</sub> = 50 Ω)	t <sub>d(off)</sub>	-	16	-	
Fall Time		t <sub>f</sub>	-	8.0	-	
Gate Charge (See Figure 6)		QT	-	6000	-	рС
SOURCE-DRAIN DIODE CHARAC	TERISTICS					
Continuous Current	۱ <sub>S</sub>	-	-	0.6	А	
Pulsed Current	I <sub>SM</sub>	-	-	0.75	_	
		1		1	t	1

 Pulsed Current
 I<sub>SM</sub>
 0.75

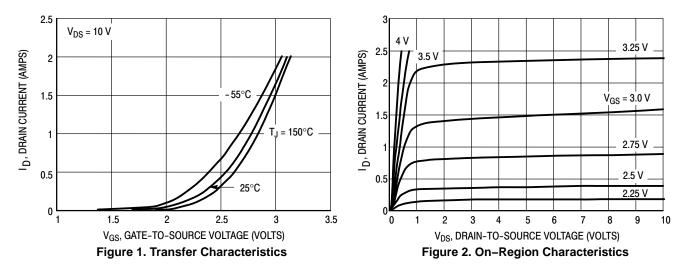
 Forward Voltage (Note 2)
 V<sub>SD</sub>
 0.8
 V

 Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%.

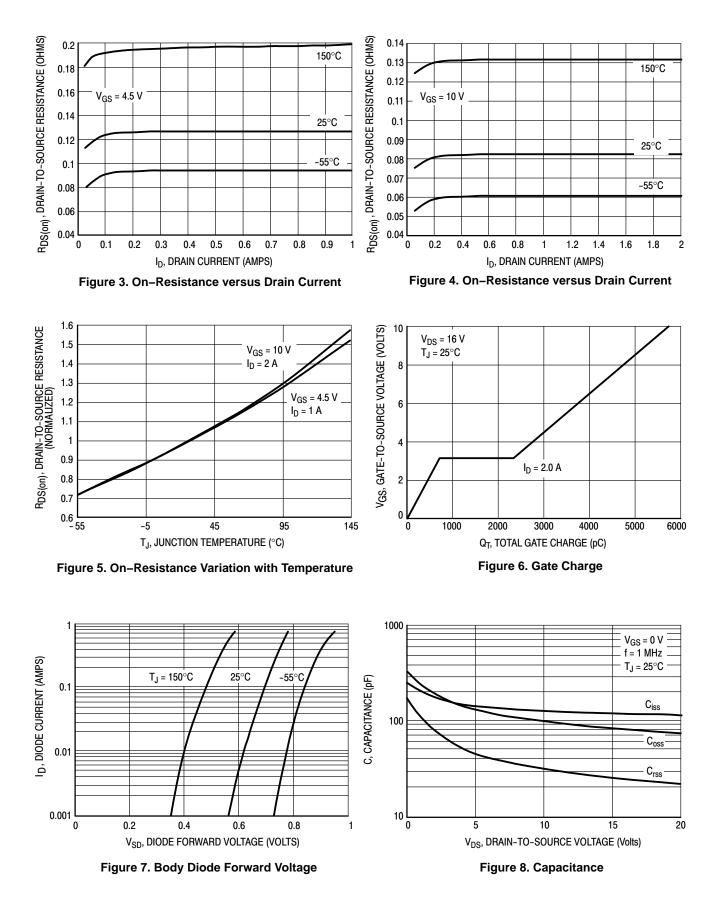
2. Switching characteristics are independent of operating junction temperature.



## **TYPICAL ELECTRICAL CHARACTERISTICS**

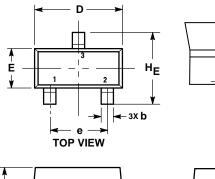
# MGSF1N02L, MVGSF1N02L

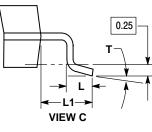
## TYPICAL ELECTRICAL CHARACTERISTICS

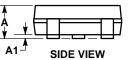


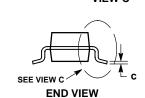
#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR** 









NOTES:

- 1
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF З.
- THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS

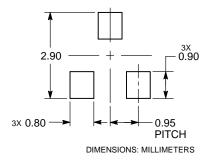
PROTRUSIONS, OR GATE BURRS.						
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
c	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10 °	0 °		10 °

STYLE 21: PIN 1. GATE

2. SOURCE

DRAIN 3.

RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="http://www.onsemi.com/site/pdl/Patent-Marking.pdf">www.onsemi.com/site/pdl/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative